

LMV931 Single/LMV932 Dual/ LMV934 Quad

1.8V, RRIO Operational Amplifiers

General Description

The LMV931/LMV932/LMV934 are low voltage, low power operational amplifiers. LMV931/LMV932/LMV934 operate from +1.8V to +5.5V supply voltages and have rail-to-rail input and output. LMV931/LMV932/LMV934 input common mode voltage extends 200mV beyond the supplies which enables user enhanced functionality beyond the supply voltage range. The output can swing rail-to-rail unloaded and within 105mV from the rail with 600Ω load at 1.8V supply. The LMV931/LMV932/LMV934 are optimized to work at 1.8V which make them ideal for portable two-cell battery powered systems and single cell Li-lon systems.

LMV931/LMV932/LMV934 exhibit excellent speed-power ratio, achieving 1.4MHz gain bandwidth product at 1.8V supply voltage with very low supply current. The LMV931/LMV932/LMV934 are capable of driving a 600Ω load and up to 1000pF capacitive load with minimal ringing. LMV931/LMV932/LMV934 have a high DC gain of 101dB, making them suitable for low frequency applications.

The single LMV931 is offered in space saving 5-Pin SC70 and SOT23 packages. The dual LMV932 are in 8-Pin MSOP and SOIC packages and the quad LMV934 are in 14-Pin TSSOP and SOIC packages. These small packages are ideal solutions for area constrained PC boards and portable electronics such as cellular phones and PDAs.

Features

(Typical 1.8V Supply Values; Unless Otherwise Noted)

- Guaranteed 1.8V, 2.7V and 5V specifications
- Output swing

V_{CM} 200mV beyond rails

■ Supply current (per channel) 100µA
■ Gain bandwidth product 1.4MHz

■ Maximum V_{OS} 4.0mV

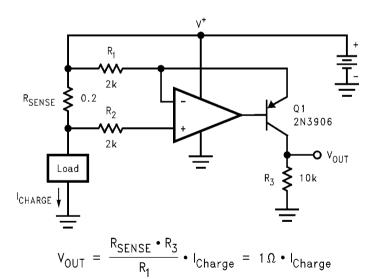
■ Ultra tiny packages

■ Temperature range —40°C to 125°C

Applications

- Consumer communication
- Consumer computing
- PDAs
- Audio pre-amp
- Portable/battery-powered electronic equipment
- Supply current monitoring
- Battery monitoring

Typical Application



200326h0

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.

ESD Tolerance (Note 2)

Charged Device Model 750V Machine Model 200V 2000V **Human Body Model** Supply Voltage (V+-V-) 6V Differential Input Voltage ± Supply Voltage Voltage at Input/Output Pins V++0.3V, V- -0.3V Storage Temperature Range -65°C to 150°C Junction Temperature (Note 4) 150°C

For soldering specifications:

See product folder at www.ti.com and www.ti.com/lit/an/snoa549c/snoa549c.pdf.

Operating Ratings (Note 1)

Supply Voltage Range 1.8V to 5.5V Temperature Range -40°C to 125°C

Thermal Resistance (θ_{.IA})

5-Pin SC70 414°C/W
5-Pin SOT23 265°C/W
8-Pin MSOP 235°C/W
8-Pin SOIC 175°C/W
14-Pin TSSOP 155°C/W
14-Pin SOIC 127°C/W

1.8V DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}C$. $V^+ = 1.8V$, $V^- = 0V$, $V_{CM} = V^+/2$, $V_O = V^+/2$ and $R_I > 1$ M Ω . **Boldface** limits apply at the temperature extremes. See (*Note 10*)

Symbol	Parameter	Cone	dition	Min (<i>Note 6</i>)	Typ (<i>Note 5</i>)	Max (Note 6)	Units	
V _{OS}	Input Offset Voltage	LMV931 (Single)		,	1	4 6	mV	
		LMV932 (Dual) LMV934 (Quad)			1	5.5 7.5	mV	
TCV _{OS}	Input Offset Voltage Average Drift				5.5		μV/°C	
I _B	Input Bias Current				15	35 50	nA	
I _{os}	Input Offset Current				13	25 40	nA	
I _S	Supply Current (per channel)				103	185 205	μΑ	
CMRR	Common Mode Rejection Ratio	LMV931, $0 \le V_{CI}$ 1.4V $\le V_{CM} \le 1.8$		60 55	78			
		LMV932 and LM $0 \le V_{CM} \le 0.6V$ $1.4V \le V_{CM} \le 1.8$		55 50	76		dB	
		$-0.2V \le V_{CM} \le 0$ $1.8V \le V_{CM} \le 2.0$	V	50	72		1	
PSRR	Power Supply Rejection Ratio	1.8V ≤ V+ ≤ 5V		75 70	100		dB	
CMVR	Input Common-Mode Voltage Range	For CMRR Range ≥ 50dB	$T_A = 25^{\circ}C$ $T_A - 40^{\circ}C \text{ to } 85^{\circ}C$ $T_A = 125^{\circ}C$	V0.2 V- V-+0.2	-0.2 to 2.1	V+ +0.2 V+ V+ -0.2	V	
A _V	Large Signal Voltage Gain LMV931 (Single)	$R_L = 600\Omega \text{ to } 0.9$ $V_O = 0.2 \text{V to } 1.6 \text{V}$		77 73	101			
		$R_L = 2k\Omega \text{ to } 0.9V$ $V_O = 0.2V \text{ to } 1.6V$		80 75	105		- dB	
	Large Signal Voltage Gain LMV932 (Dual)	$R_L = 600\Omega$ to 0.9V, $V_O = 0.2V$ to 1.6V, $V_{CM} = 0.5V$ $R_L = 2k\Omega$ to 0.9V, $V_O = 0.2V$ to 1.6V, $V_{CM} = 0.5V$		75 72	90		dB	
	LMV934 (Quad)			78 75	100		l ub	

Symbol	Parameter	Condition	Min (<i>Note 6</i>)	Typ (<i>Note 5</i>)	Max (Note 6)	Units
V _O Output	Output Swing	$R_{L} = 600\Omega \text{ to } 0.9V$ $V_{IN} = \pm 100 \text{mV}$	1.65 1.63	1.72		
				0.077	0.105 0.120	.,
		$R_L = 2k\Omega$ to 0.9V $V_{IN} = \pm 100$ mV	1.75 1.74	1.77		V
				0.024	0.035 0.04	
I _O	Output Short Circuit Current (Note 3)	Sourcing, V _O = 0V V _{IN} = 100mV	4 3.3	8		m A
		Sinking, $V_O = 1.8V$ $V_{IN} = -100 \text{mV}$	7 5	9		mA

1.8V AC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}C$. $V^+ = 1.8V$, $V^- = 0V$, $V_{CM} = V^+/2$, $V_O = V^+/2$ and $R_L > 1$ M Ω . **Boldface** limits apply at the temperature extremes. See (*Note 10*)

Symbol	Parameter	Conditions	Min (<i>Note 6</i>)	Typ (<i>Note 5</i>)	Max (Note 6)	Units
SR	Slew Rate	(Note 7)		0.35		V/µs
GBW	Gain-Bandwidth Product			1.4		MHz
Φ _m	Phase Margin			67		deg
G _m	Gain Margin			7		dB
e _n	Input-Referred Voltage Noise	f = 10 kHz, V _{CM} = 0.5V		60		nV √Hz
i _n	Input-Referred Current Noise	f = 10 kHz		0.08		pA √Hz
THD	Total Harmonic Distortion	$f = 1kHz$, $A_V = +1$ $R_L = 600\Omega$, $V_{IN} = 1$ V_{PP}		0.023		%
	Amp-to-Amp Isolation	(Note 9)		123		dB

2.7V DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_J = 25°C. V^+ = 2.7V, V^- = 0V, V_{CM} = V+/2, V_O = V+/2 and R_L > 1 M Ω . **Boldface** limits apply at the temperature extremes. See (*Note 10*)

Symbol	Parameter	Condition		Min (Note 6)	Typ (<i>Note 5</i>)	Max (Note 6)	Units	
V _{OS}	Input Offset Voltage	LMV931 (Single)			1	4 6	mV	
		LMV932 (Dual) LMV934 (Quad)			1	5.5 7.5	mV	
TCV _{OS}	Input Offset Voltage Average Drift		,		5.5		μV/°C	
I _B	Input Bias Current				15	35 50	nA	
l _{os}	Input Offset Current				8	25 40	nA	
I _S	Supply Current (per channel)				105	190 210	μA	
CMRR	Common Mode Rejection Ratio	$2.3V \le V_{CM} \le 2.7$	7V (<i>Note 8</i>)	60 55	81			
		LMV932 and LM' $0 \le V_{CM} \le 1.5V$ $2.3V \le V_{CM} \le 2.7$		55 50	80		dB	
		$-0.2V \le V_{CM} \le 0$ $2.7V \le V_{CM} \le 2.9$		50	74			
PSRR	Power Supply Rejection Ratio	1.8V ≤ V+ ≤ 5V V _{CM} = 0.5V		75 70	100		dB	
V _{CM}	Input Common-Mode Voltage Range	For CMRR Range ≥ 50dB	$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C \text{ to}$ $85^{\circ}C$	V0.2 V-	-0.2 to 3.0	V+ +0.2 V+	V	
A _V	Large Signal Voltage Gain	$R_{L} = 600\Omega$ to 1.3	T _A = 125°C 5V,	V- +0.2 87	104	V+ -0.2		
•	LMV931 (Single)	$V_0 = 0.2V \text{ to } 2.5V$ $R_1 = 2k\Omega \text{ to } 1.35$	J	86 92	110		dB	
		$V_0 = 0.2V \text{ to } 2.5V$	J	91				
	Large Signal Voltage Gain LMV932 (Dual)	$R_L = 600\Omega \text{ to } 1.3$ $V_O = 0.2V \text{ to } 2.5V$		78 75	90		dB	
	LMV934 (Quad)	$R_L = 2k\Omega \text{ to } 1.35$ $V_O = 0.2V \text{ to } 2.5V$		81 78	100		uБ	
V _O	Output Swing	$R_L = 600\Omega \text{ to } 1.3$ $V_{IN} = \pm 100 \text{mV}$	5V	2.55 2.53	2.62			
		IIV			0.083	0.110 0.130		
		$R_L = 2k\Omega$ to 1.35 $V_{IN} = \pm 100$ mV	V	2.65 2.64	2.675		V	
					0.025	0.04 0.045		
lo	Output Short Circuit Current (Note 3)	Sourcing, $V_O = 0$ $V_{IN} = 100 \text{mV}$	v	20 30 15			A	
		Sinking, $V_0 = 0V$ $V_{IN} = -100 \text{mV}$		18 12	25		mA	

2.7V AC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}C$. $V^+ = 2.7V$, $V^- = 0V$, $V_{CM} = 1.0V$, $V_O = 1.35V$ and $R_L > 1$ M Ω . **Boldface** limits apply at the temperature extremes. See (*Note 10*)

Symbol	Parameter	Conditions	Min (Note 6)	Typ (Note 5)	Max (Note 6)	Units
SR	Slew Rate	(Note 7)		0.4		V/µs
GBW	Gain-Bandwidth Product			1.4		MHz
Φ _m	Phase Margin			70		deg
G _m	Gain Margin			7.5		dB
e _n	Input-Referred Voltage Noise	$f = 10 \text{ kHz}, V_{CM} = 0.5V$		57		nV √Hz
i _n	Input-Referred Current Noise	f = 10 kHz		0.08		pA √Hz
THD	Total Harmonic Distortion	$f = 1kHz$, $A_V = +1$ $R_L = 600\Omega$, $V_{IN} = 1V_{PP}$		0.022		%
	Amp-to-Amp Isolation	(Note 9)		123		dB

5V DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_J = 25°C. V+ = 5V, V = 0V, V_{CM} = V+/2, V_O = V+/2 and R_L > 1 M Ω . **Boldface** limits apply at the temperature extremes. See (*Note 10*)

Symbol	Parameter	Condition		Min (Note 6)	Typ (<i>Note 5</i>)	Max (Note 6)	Units	
V _{OS}	Input Offset Voltage	LMV931 (Single)	LMV931 (Single)		1	4 6	mV	
		LMV932 (Dual) LMV934 (Quad)			1	5.5 7.5	mV	
TCV _{OS}	Input Offset Voltage Average Drift				5.5		μV/°C	
I _B	Input Bias Current				14	35 50	nA	
I _{os}	Input Offset Current				9	25 40	nA	
I _S	Supply Current (per channel)				116	210 230	μΑ	
CMRR	Common Mode Rejection Ratio	$0 \le V_{CM} \le 3.8V$ $4.6V \le V_{CM} \le 5.0$)V (<i>Note 8</i>)	60 55	86		dB	
		$-0.2V \le V_{CM} \le 0$ $5.0V \le V_{CM} \le 5.2$		50	78		ив	
PSRR	Power Supply Rejection Ratio	1.8V ≤ V+ ≤ 5V V _{CM} = 0.5V		75 70	100		dB	
CMVR	Input Common-Mode Voltage Range	For CMRR Range ≥ 50dB	$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C$ to $85^{\circ}C$	V0.2 V-	-0.2 to 5.3	V+ +0.2 V+	v	
			T _A = 125°C	V- +0.3	-	V+ -0.3	1	
A_V	Large Signal Voltage Gain LMV931 (Single)	$R_L = 600\Omega$ to 2.5 $V_O = 0.2V$ to 4.8		88 87	102			
		$R_L = 2k\Omega \text{ to } 2.5V$ $V_O = 0.2V \text{ to } 4.8V$		94 93	113		dB	
	Large Signal Voltage Gain LMV932 (Dual)	$R_L = 600\Omega$ to 2.5 $V_O = 0.2V$ to 4.8		81 78	90			
	LMV934 (Quad)	$R_L = 2k\Omega \text{ to } 2.5V$ $V_O = 0.2V \text{ to } 4.8V$		85 82	100		- dB	
V _O	Output Swing	$R_L = 600\Omega \text{ to } 2.5$ $V_{IN} = \pm 100 \text{mV}$		4.855 4.835	4.890			
					0.120	0.160 0.180	v	
		$R_L = 2k\Omega$ to 2.5V $V_{IN} = \pm 100$ mV		4.945 4.935	4.967		V	
					0.037	0.065 0.075		
I _O	Output Short Circuit Current (Note 3)	LMV931, Sourcin V _{IN} = 100mV		80 68	100		m ^	
		Sinking, $V_O = 5V$ $V_{IN} = -100 \text{mV}$		58 45	65		mA	

5V AC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}C$. $V^+ = 5V$, $V^- = 0V$, $V_{CM} = V^+/2$, $V_O = 2.5V$ and $R_L > 1$ M Ω . **Boldface** limits apply at the temperature extremes. See (*Note 10*)

Symbol	Parameter	Conditions	Min (Note 6)	Typ (<i>Note 5</i>)	Max (Note 6)	Units
SR	Slew Rate	(Note 7)		0.42		V/µs
GBW	Gain-Bandwidth Product			1.5		MHz
Φ_{m}	Phase Margin			71		deg
G _m	Gain Margin			8		dB
e _n	Input-Referred Voltage Noise	f = 10 kHz, V _{CM} = 1V		50		nV √Hz
i _n	Input-Referred Current Noise	f = 10 kHz		0.08		pA √Hz
THD	Total Harmonic Distortion	$f = 1kHz$, $A_V = +1$ $R_L = 600\Omega$, $V_O = 1V_{PP}$		0.022		%
	Amp-to-Amp Isolation	(Note 9)		123		dB

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.

Note 2: Human Body Model, applicable std. MIL-STD-883, Method 3015.7. Machine Model, applicable std. JESD22-A115-A (ESD MM std. of JEDEC) Field-Induced Charge-Device Model, applicable std. JESD22-C101-C (ESD FICDM std. of JEDEC).

Note 3: Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of 45mA over long term may adversely affect reliability.

Note 4: The maximum power dissipation is a function of $T_{J(MAX)}$, θ_{JA} and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} - T_A) / \theta_{JA}$. All numbers apply for packages soldered directly onto a PC Board.

Note 5: Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.

Note 6: All limits are guaranteed by testing or statistical analysis.

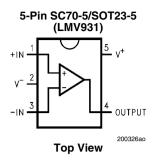
Note 7: Connected as voltage follower with input step from V- to V+. Number specified is the slower of the positive and negative slew rates.

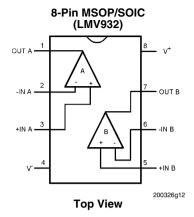
Note 8: For guaranteed temperature ranges, see Input Common-Mode Voltage Range specifications.

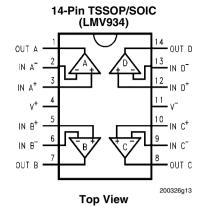
Note 9: Input referred, $R_L = 100 k\Omega$ connected to V+/2. Each amp excited in turn with 1kHz to produce $V_O = 3V_{PP}$ (For Supply Voltages <3V, $V_O = V^+$).

Note 10: Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$. See Applications section for information of temperature derating of the device. Absolute Maximum Ratings indicated junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.

Connection Diagrams





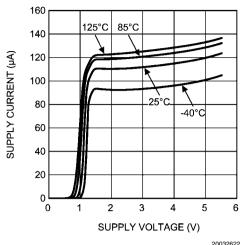


Ordering Information

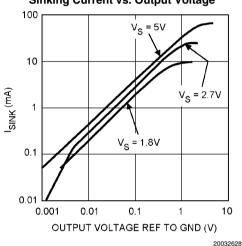
Package	Part Number	Packaging Marking	Transport Media	NSC Drawing	
5-Pin SC70	LMV931MG	LMV931MG A74		MAA05A	
5-FIII 3C/U	LMV931MGX	A/4	3k Units Tape and Reel	IVIAAUSA	
5-Pin SOT23	LMV931MF	- A79A	1k Units Tape and Reel	MF05A	
5-7111 50123	LMV931MFX	A79A	3k Units Tape and Reel	IVIFUSA	
8-Pin MSOP	LMV932MM	- A86A	1k Units Tape and Reel	MUA08A	
6-PIII WISOP	LMV932MMX	AOOA	3.5k Units Tape and Reel		
8-Pin SOIC	LMV932MA	- LMV932MA	Rails	M08A	
6-PIII 50IC	LMV932MAX	LIVI V 932IVIA	2.5k Units Tape and Reel	IVIUSA	
14-Pin TSSOP	LMV934MT	- LMV934MT	Rails	MTC14	
14-PIII 1550P	LMV934MTX	LIVIV934IVII	2.5k Units Tape and Reel	T WITCI4	
14-Pin SOIC	LMV934MA	- LMV934MA	Rails	M14A	
14-7111 5010	LMV934MAX	LIVI V 934IVIA	2.5k Units Tape and Reel] IVIT4A	

Typical Performance Characteristics Unless otherwise specified, $V_S = +5V$, single supply, $T_A = 25$ °C.

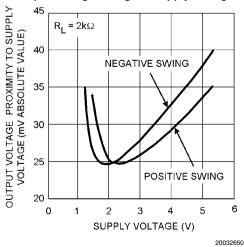
Supply Current vs. Supply Voltage (LMV931)



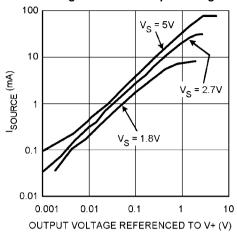
Sinking Current vs. Output Voltage



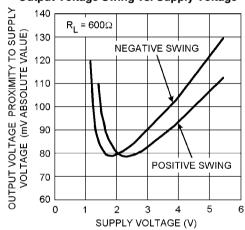
Output Voltage Swing vs. Supply Voltage



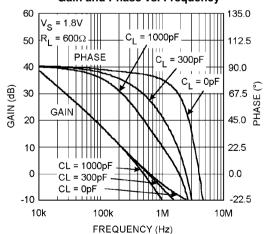
Sourcing Current vs. Output Voltage



Output Voltage Swing vs. Supply Voltage



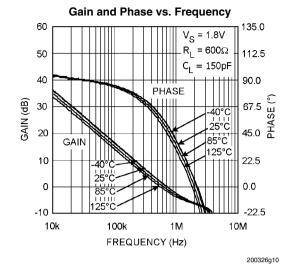
Gain and Phase vs. Frequency



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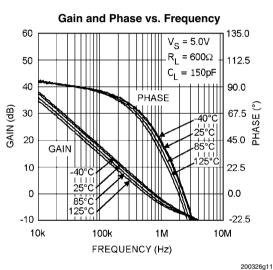
Gain and Phase vs. Frequency 135.0 = 5.0V**=** 600Ω 50 112.5 **PHASE** C_L = 300pF 40 90.0 67.5 (°) 45.0 A GAIN (dB) 30 GAIN 20 10 22.5 CL = 1000pF 0 0.0 CL = 300pF CL = 0pF -22.5 -10 10M 10k 100k 1M FREQUENCY (Hz)

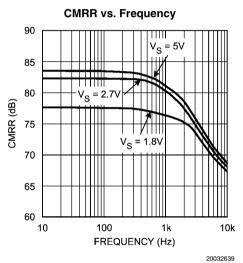


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10k

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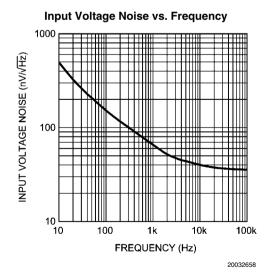
PSRR vs. Frequency

100
90
80
80
70
-PSRR
-PSRR
-PSRR
40

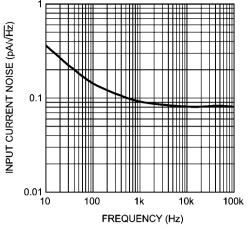
FREQUENCY (Hz)

30

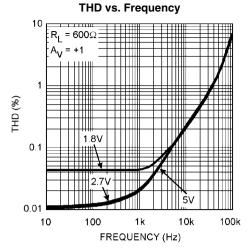
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Input Current Noise vs. Frequency

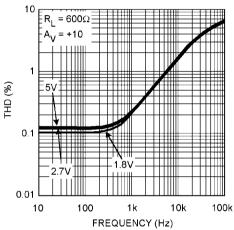


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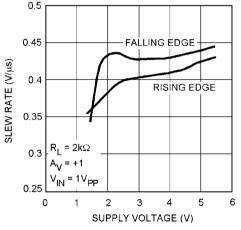
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THD vs. Frequency



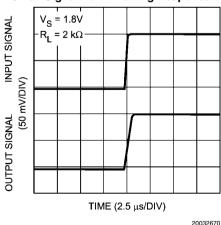
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Slew Rate vs. Supply Voltage 0.5

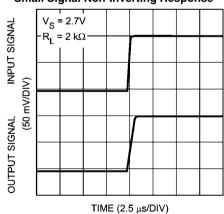


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Small Signal Non-Inverting Response

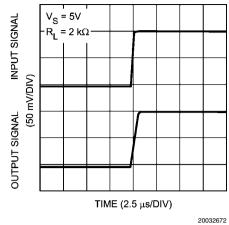


Small Signal Non-Inverting Response

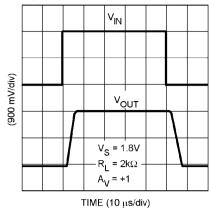


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Small Signal Non-Inverting Response

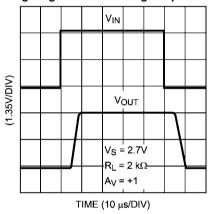


Large Signal Non-Inverting Response

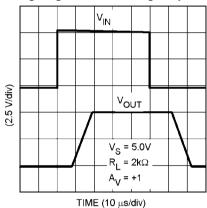


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Large Signal Non-Inverting Response



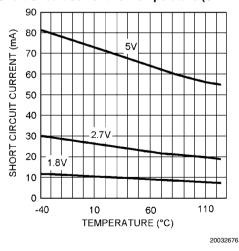
Large Signal Non-Inverting Response



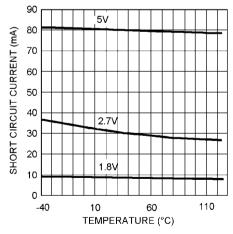
20032675

Short Circuit Current vs. Temperature (Sinking)

20032674

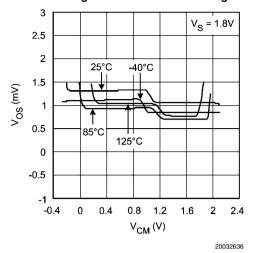


Short Circuit Current vs. Temperature (Sourcing)

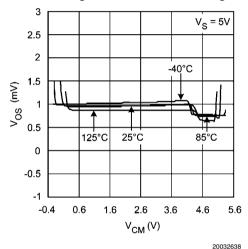


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Offset Voltage vs. Common Mode Range



Offset Voltage vs. Common Mode Range



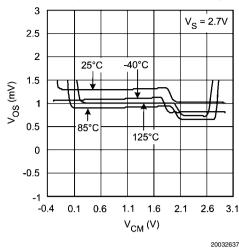
Application Note

INPUT AND OUTPUT STAGE

The rail-to-rail input stage of this family provides more flexibility for the designer. The LMV931/LMV932/LMV934 use a complimentary PNP and NPN input stage in which the PNP stage senses common mode voltage near V- and the NPN stage senses common mode voltage near V+. The transition from the PNP stage to NPN stage occurs 1V below V+. Since both input stages have their own offset voltage, the offset of the amplifier becomes a function of the input common mode voltage and has a crossover point at 1V below V+.

This V_{OS} crossover point can create problems for both DC and AC coupled signals if proper care is not taken. Large input signals that include the V_{OS} crossover point will cause distortion in the output signal. One way to avoid such distortion is to keep the signal away from the crossover. For example, in a unity gain buffer configuration and with $V_S = 5V$, a 5V peak-to-peak signal will contain input-crossover distortion while a 3V peak-to-peak signal centered at 1.5V will not contain input-crossover distortion as it avoids the crossover point. Another way to avoid large signal distortion is to use a gain of -1 circuit which avoids any voltage excursions at the input terminals of the amplifier. In that circuit, the common mode DC voltage can be set at a level away from the V_{OS} cross-over point. For small signals, this transition in V_{OS} shows up as a V_{CM} de-

Offset Voltage vs. Common Mode Range



pendent spurious signal in series with the input signal and can effectively degrade small signal parameters such as gain and common mode rejection ratio. To resolve this problem, the small signal should be placed such that it avoids the V_{OS} crossover point. In addition to the rail-to-rail performance, the output stage can provide enough output current to drive 600Ω loads. Because of the high current capability, care should be taken not to exceed the 150°C maximum junction

INPUT BIAS CURRENT CONSIDERATION

temperature specification.

The LMV931/LMV932/LMV934 family has a complementary bipolar input stage. The typical input bias current (I_B) is 15nA. The input bias current can develop a significant offset voltage. This offset is primarily due to I_B flowing through the negative feedback resistor, R_F . For example, if I_B is 50nA and R_F is 100k Ω , then an offset voltage of 5mV will develop ($V_{OS} = I_B \times R_F$). Using a compensation resistor (R_C), as shown in Figure 1, cancels this effect. But the input offset current (I_{OS}) will still contribute to an offset voltage in the same manner.

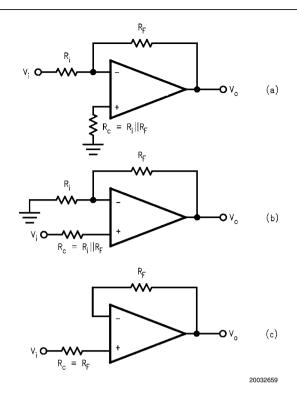


FIGURE 1. Canceling the Offset Voltage due to Input Bias
Current

Typical Applications

HIGH SIDE CURRENT SENSING

The high side current sensing circuit (*Figure 2*) is commonly used in a battery charger to monitor charging current to prevent over charging. A sense resistor R_{SENSE} is connected to the battery directly. This system requires an op amp with rail-to-rail input. The LMV931/LMV932/LMV934 are ideal for this application because its common mode input range goes up to the rail.

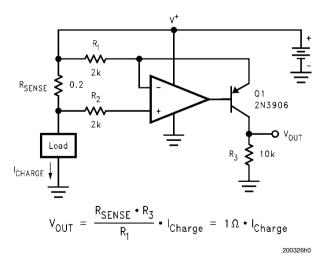


FIGURE 2. High Side Current Sensing

HALF-WAVE RECTIFIER WITH RAIL-TO-GROUND OUTPUT SWING

Since the LMV931/LMV932/LMV934 input common mode range includes both positive and negative supply rails and the output can also swing to either supply, achieving half-wave rectifier functions in either direction is an easy task. All that is needed are two external resistors; there is no need for diodes or matched resistors. The half wave rectifier can have either positive or negative going outputs, depending on the way the circuit is arranged.

In *Figure 3* the circuit is referenced to ground, while in *Figure 4* the circuit is biased to the positive supply. These configurations implement the half wave rectifier since the LMV931/LMV932/LMV934 can not respond to one-half of the incoming waveform. It can not respond to one-half of the incoming because the amplifier can not swing the output beyond either rail therefore the output disengages during this half cycle. During the other half cycle, however, the amplifier achieves a half wave that can have a peak equal to the total supply voltage. R₁ should be large enough not to load the LMV931/LMV932/LMV934.

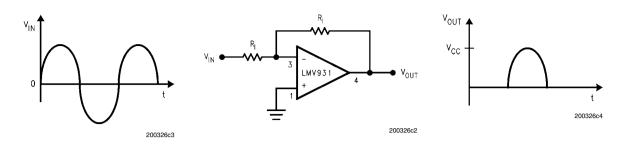


FIGURE 3. Half-Wave Rectifier with Rail-To-Ground Output Swing Referenced to Ground

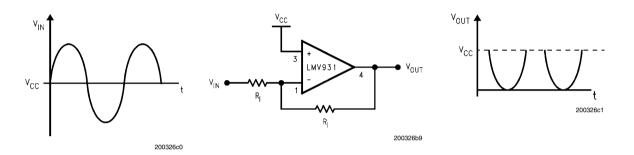


FIGURE 4. Half-Wave Rectifier with Negative-Going Output Referenced to V_{CC}

INSTRUMENTATION AMPLIFIER WITH RAIL-TO-RAIL INPUT AND OUTPUT

Some manufactures make a non-"rail-to-rail"-op amp rail-to-rail by using a resistive divider on the inputs. The resistors divide the input voltage to get a rail-to-rail input range. The problem with this method is that it also divides the signal, so in order to get the obtained gain, the amplifier must have a higher closed loop gain. This raises the noise and drift by the internal gain factor and lowers the input impedance. Any mismatch in these precision resistors reduces the CMRR as well. The LMV931/LMV932/LMV934 is rail-to-rail and therefore doesn't have these disadvantages.

Using three of the LMV931/LMV932/LMV934 amplifiers, an instrumentation amplifier with rail-to-rail inputs and outputs can be made as shown in *Figure 5*.

In this example, amplifiers on the left side act as buffers to the differential stage. These buffers assure that the input impedance is very high and require no precision matched resistors in the input stage. They also assure that the difference amp is driven from a voltage source. This is necessary to maintain the CMRR set by the matching R_1 - R_2 with R_3 - R_4 . The gain is set by the ratio of R_2/R_1 and R_3 should equal R_1 and R_4 equal R_2 . With both rail-to-rail input and output ranges,

the input and output are only limited by the supply voltages. Remember that even with rail-to-rail outputs, the output can not swing past the supplies so the combined common mode voltages plus the signal should not be greater that the supplies or limiting will occur. For additional applications, see National Semiconductor application notes AN–29, AN–31, AN–71, and AN–127.

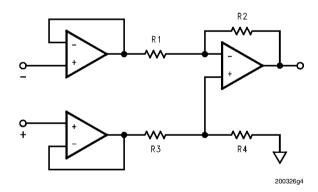
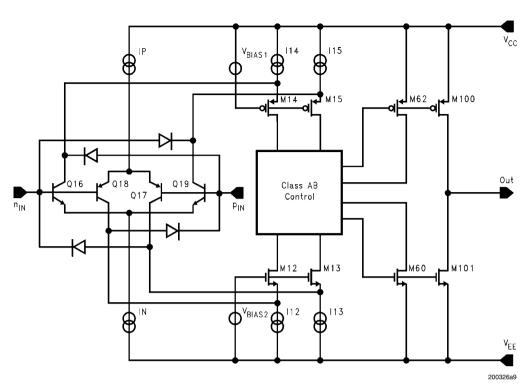
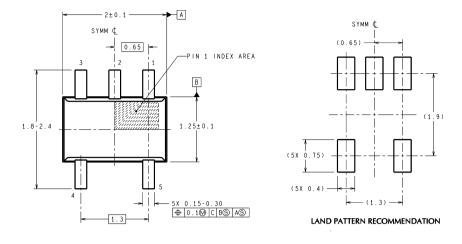


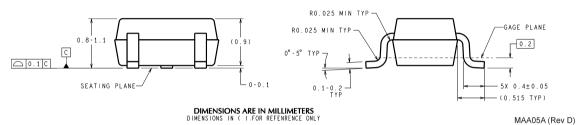
FIGURE 5. Rail-to-rail Instrumentation Amplifier

Simplified Schematic

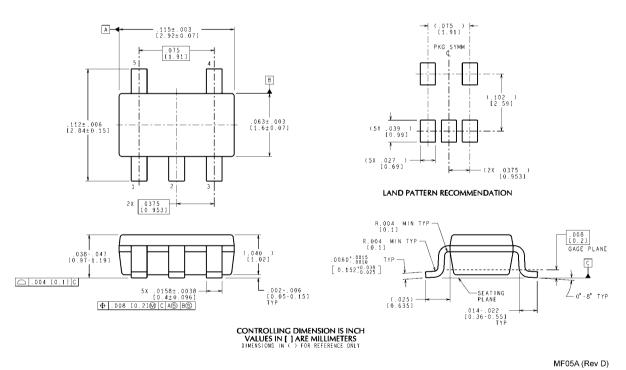


Physical Dimensions inches (millimeters) unless otherwise noted

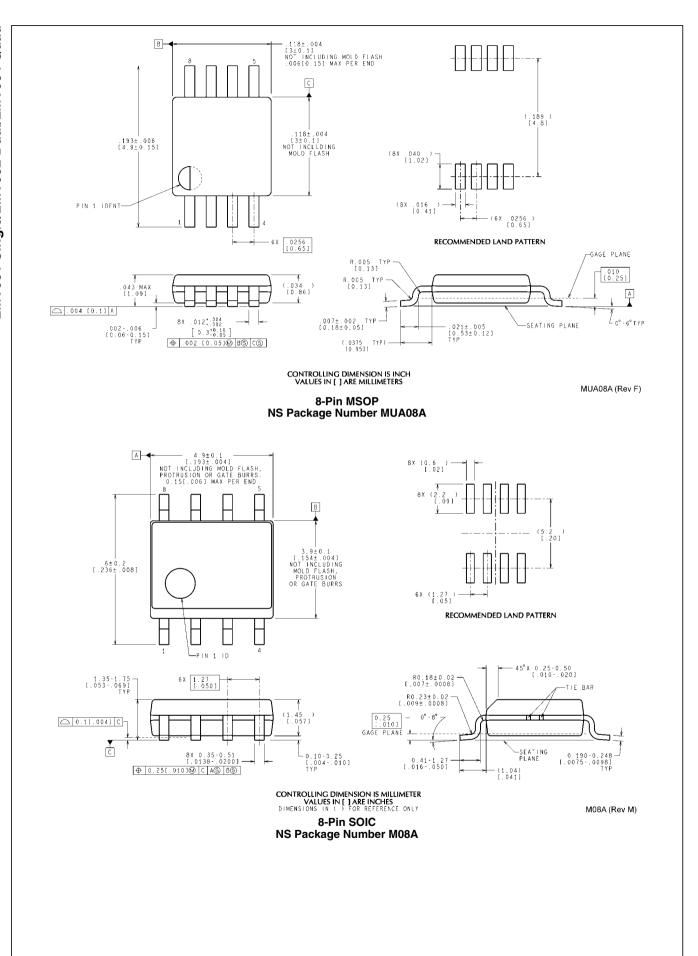


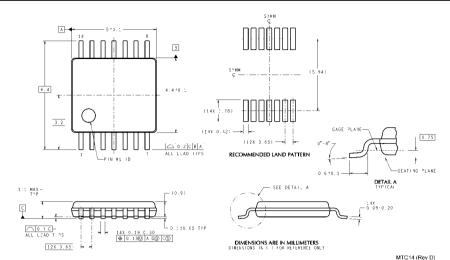


5-Pin SC70 NS Package Number MAA05A

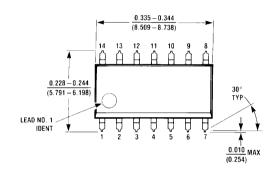


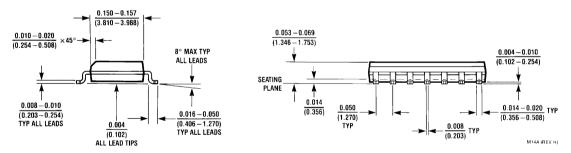
5-Pin SOT23 NS Package Number MF05A





14-Pin TSSOP NS Package Number MTC14





14-Pin SOIC NS Package Number M14A

ifiers	Notes
Ampl	
Operational	
RRIC	
LMV931 Single/LMV932 Dual/LMV934 Quad 1.8V, RRIO Operational Amplifiers	
LMV931 Single/LMV	

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